

CMOS 4-Stage Parallel In/Parallel Out Shift Register

with J-K Serial Inputs and True/Complement Outputs

High-Voltage Types (20-Volt Rating)

■ CD4035B is a four-stage clocked signal serial register with provision for synchronous PARALLEL inputs to each stage and SERIAL inputs to the first stage via JK logic. Register stages 2, 3, and 4 are coupled in a serial D flip-flop configuration when the register is in the serial mode (PARALLEL/SERIAL control low).

Parallel entry into each register stage is permitted when the PARALLEL/SERIAL control is high.

In the parallel or serial mode information is transferred on positive clock transitions.

When the TRUE/COMPLEMENT control is high, the true contents of the register are available at the output terminals. When the TRUE/COMPLEMENT control is low, the outputs are the complements of the data in the register. The TRUE/COMPLEMENT control functions asynchronously with respect to the CLOCK-signal.

J-K input logic is provided on the first stage SERIAL input to minimize logic requirements particularly in counting and sequence-generation applications. With JK inputs connected together, the first stage becomes a D flip-flop. An asynchronous common RESET is also provided.

The CD4035B types are supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dual-in-line plastic packages (E suffix), and in chip form (H suffix).

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V_{DD})

Voltages referenced to V_{SS} Terminal -0.5V to +20V

INPUT VOLTAGE RANGE, ALL INPUTS -0.5V to V_{DD} +0.5V

DC INPUT CURRENT, ANY ONE INPUT ±10mA

POWER DISSIPATION PER PACKAGE (P_D):

For T_A = -55°C to +100°C 500mW

For T_A = +100°C to +125°C Derate Linearly at 12mW/°C to 200mW

DEVICE DISSIPATION PER OUTPUT TRANSISTOR

FOR T_A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW

OPERATING-TEMPERATURE RANGE (T_A) -55°C to +125°C

STORAGE TEMPERATURE RANGE (T_{stg}) -65°C to +150°C

LEAD TEMPERATURE (DURING SOLDERING):

At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max +265°C

Features:

- 4-Stage clocked shift operation
- Synchronous parallel entry on all 4 stages
- JK inputs on first stage
- Asynchronous True/Complement control on all outputs
- Static flip-flop operation; Master-slave configuration
- Buffered inputs and outputs
- High speed — 12 MHz (typ.) at V_{DD} = 10 V
- 100% tested for quiescent current at 20 V
- Standardized, symmetrical output characteristics
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of "B" Series CMOS Devices"

Applications:

- Counters, Registers
- Arithmetic-unit registers
- Shift-left — shift right registers
- Serial-to-parallel/parallel-to-serial conversions
- Sequence generation
- Control circuits
- Code conversion

FIRST STAGE TRUTH TABLE

CL	I _{n-1} (INPUTS)			Q _{n-1}	f _n (OUTPUTS)
	J	K	R		
	0	X	0	0	0
	1	X	0	0	1
	X	0	0	1	0
	1	0	0	Q _{n-1}	TOGGLE MODE
	X	1	0	1	1
	X	X	0	Q _{n-1}	Q _{n-1}
X	X	X	1	X	0

CD4035B Types

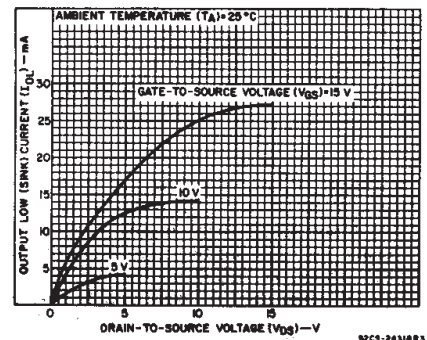
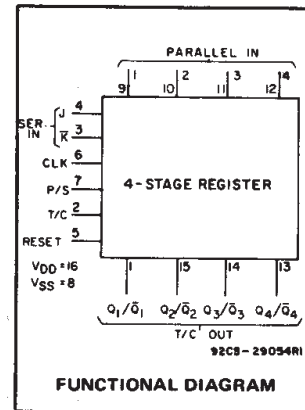


Fig. 1 — Typical output low (sink) current characteristics.

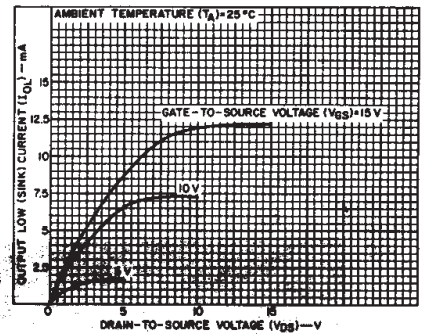


Fig. 2 — Minimum output low (sink) current characteristics.

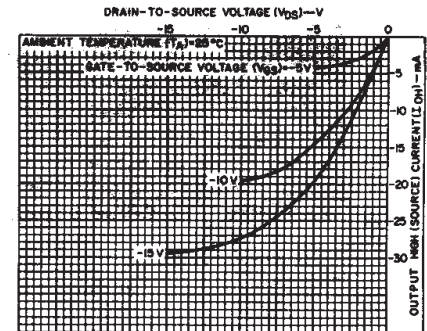


Fig. 3 — Typical output high (source) current characteristics.

CD4035B Types

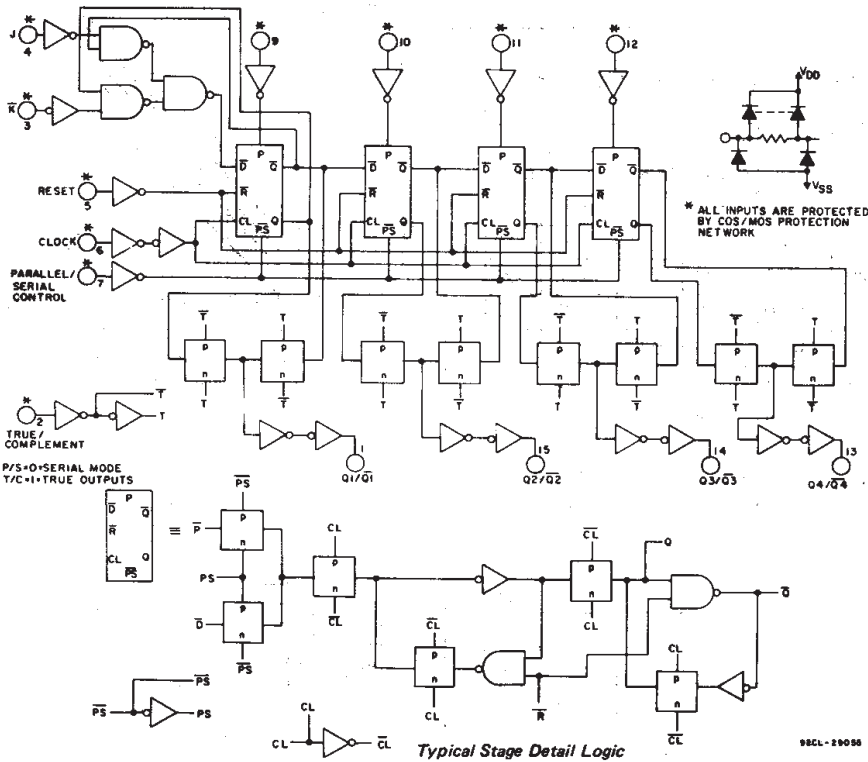


Fig. 4 - Logic diagram.

RECOMMENDED OPERATING CONDITIONS at $T_A = 25^\circ\text{C}$, Except as Noted.
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	V _{DD} (V)	LIMITS		UNITS
		MIN.	MAX.	
Supply-Voltage Range (For $T_A = \text{Full Package-Temperature Range}$)		3	18	V
Data Setup Time, t_s :				
J/ \bar{K} Lines	5 10 15	220 80 60	— — —	ns
Parallel-In Lines	5 10 15	140 50 40	— — —	ns
Clock Pulse Width, t_{W}	5 10 15	200 90 60	— — —	ns
Clock Input Frequency, f_{CL}	5 10 15	dc	2 6 8	MHz
Clock Rise or Fall Time, t_{rCL} , t_{fCL} :	5 10 15	— — —	15 15 15	μs
Reset Pulse Width, t_{W}	5 10 15	250 110 80	— — —	ns

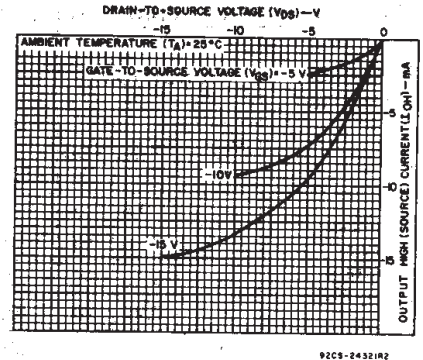


Fig. 5 - Minimum output high (source) current characteristics.

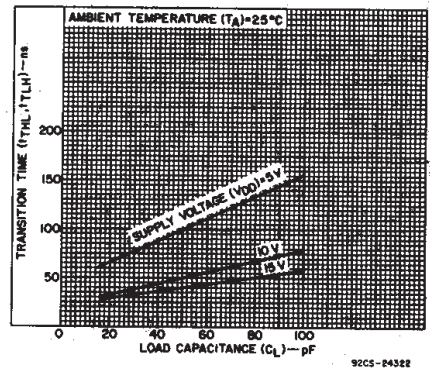


Fig. 6 - Typical transition time as a function of load capacitance.

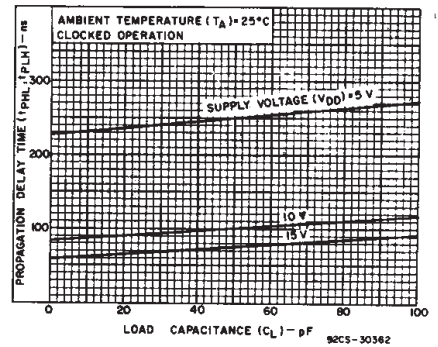


Fig. 7 - Typical propagation delay times as a function of load capacitance (Q output).

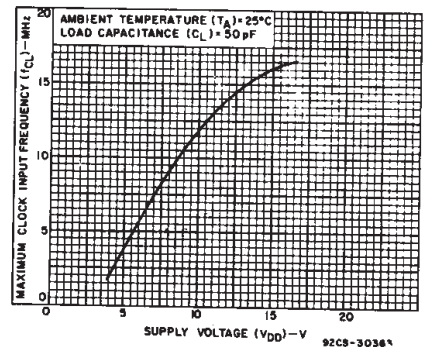


Fig. 8 - Typical maximum clock input frequency as a function of supply voltage.

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COMMERCIAL CMOS
HIGH VOLTAGE ICs

CD4035B Types

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
	V _O (V)	V _{IN} (V)	V _{DD} (V)	-55	-40	+85	+125	+25			
								Min.	Typ.	Max.	
Quiescent Device Current, I _{DD} Max.	-	0.5	5	5	5	150	150	-	0.04	5	μA
	-	0.10	10	10	10	300	300	-	0.04	10	
	-	0.15	15	20	20	600	600	-	0.04	20	
	-	0.20	20	100	100	3000	3000	-	0.08	100	
Output Low (Sink) Current, I _{OL} Min.	0.4	0.5	5	0.64	0.61	0.42	0.36	0.51	1	-	mA
	0.5	0.10	10	1.6	1.5	1.1	0.9	1.3	2.6	-	
	1.5	0.15	15	4.2	4	2.8	2.4	3.4	6.8	-	
Output High (Source) Current, I _{OH} Min.	4.6	0.5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	mA
	2.5	0.5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-	
	9.5	0.10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-	
	13.5	0.15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	-	
Output Voltage: Low-Level, V _{OL} Max.	-	0.5	5	0.05			-	0	0.05	-	V
	-	0.10	10	0.05			-	0	0.05	-	
	-	0.15	15	0.05			-	0	0.05	-	
Output Voltage: High-Level, V _{OH} Min.	-	0.5	5	4.95			-	4.95	5	-	V
	-	0.10	10	9.95			-	9.95	10	-	
	-	0.15	15	14.95			-	14.95	15	-	
Input Low Voltage, V _{IL} Max.	0.5, 4.5	-	5	1.5			-	-	1.5	-	V
	1.9	-	10	3			-	-	3	-	
	1.5, 13.5	-	15	4			-	-	4	-	
Input High Voltage, V _{IH} Min.	0.5, 4.5	-	5	3.5			-	3.5	-	-	V
	1.9	-	10	7			-	7	-	-	
	1.5, 13.5	-	15	11			-	11	-	-	
Input Current, I _{IN} Max.	-	0.18	18	±0.1	±0.1	±1	±1	-	±10 ⁻⁵	±0.1	μA

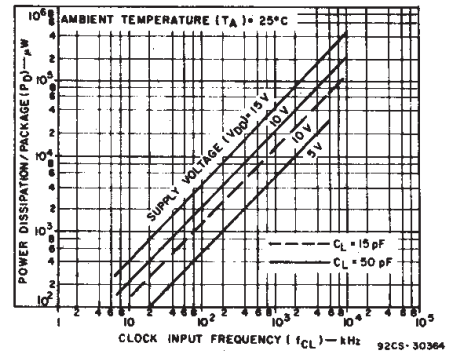


Fig. 9 - Typical dynamic power dissipation as a function of clock input frequency.

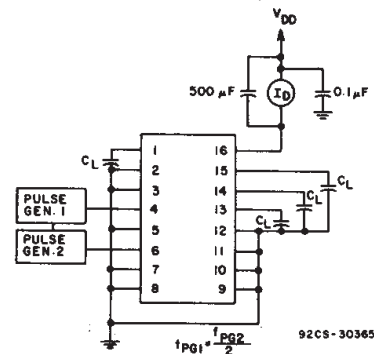


Fig. 10 - Dynamic power dissipation test circuit.

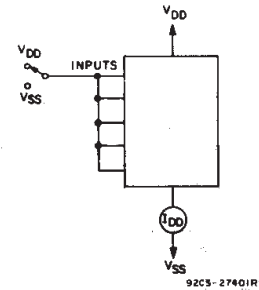


Fig. 11 - Quiescent-device current test circuit.

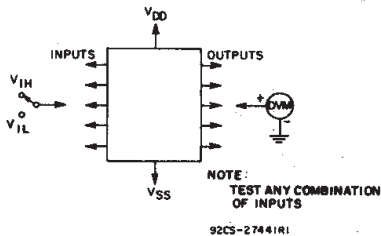


Fig. 12 - Input-voltage test circuit.

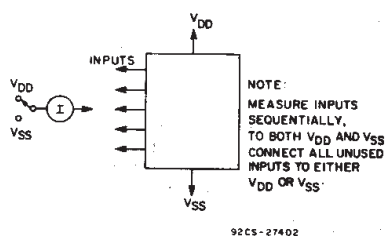


Fig. 13 - Input-current test circuit.

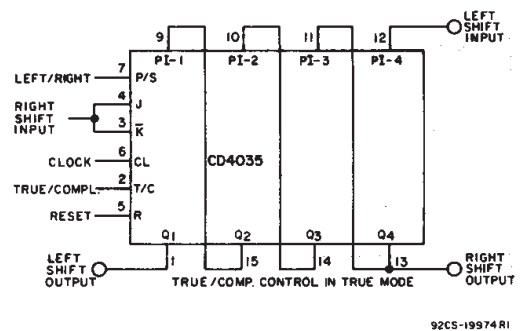
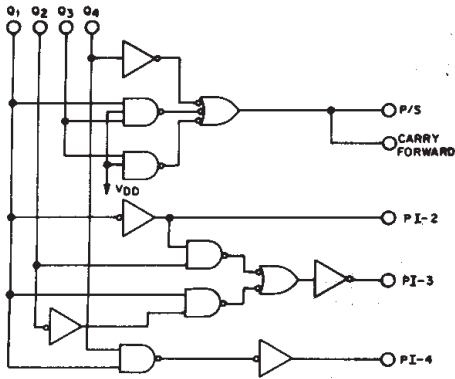


Fig. 14 - Shift left/shift right register.

CD4035B Types



Using Couleur's Technique (BIDEC)[▲], a binary number (most significant bit, MSB) first is shifted and processed, such that the BCD equivalent is obtained when the last binary bit is clocked into the register. The CD4035B, with the correct conversion logic, can also be used as a BCD-to-binary converter.

[▲]The basic rule is: If a 4 or less is in a decade, shift with the next clock pulse; if a 5 or greater is in a decade, add 3 and then shift at the next clock pulse. For more information refer to "IRE TRANSACTIONS ON ELECTRONIC COMPUTERS", Dec. 1958, Pages 313-316.

Fig. 15 - BIDEC logic.

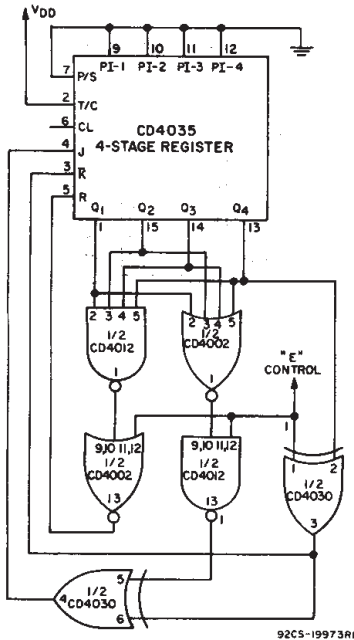


Fig. 16(a) - Double sequence generator.

DYNAMIC ELECTRICAL CHARACTERISTICS

At $T_A = 25^\circ\text{C}$, Input $t_r, t_f = 20\text{ ns}$, $C_L = 50\text{ pF}$, $R_L = 200\text{ k}\Omega$

CHARACTERISTICS	TEST CONDITIONS		LIMITS			UNITS
	V_{DD} (V)		Min.	Typ.	Max.	
CLOCKED OPERATION						
Propagation Delay Time: t_{PHL}, t_{PLH}	5	—	250	500	ns	
	10	—	100	200		
	15	—	75	150		
Transition Time: t_{THL}, t_{TLH}	5	—	100	200	ns	
	10	—	50	100		
	15	—	40	80		
Minimum Clock Pulse Width, t_{W}	5	—	100	200	ns	
	10	—	45	90		
	15	—	30	60		
Clock Rise or Fall Time, t_{rCL}, t_{fCL}^*	5, 10, 15	—	—	15	μs	
	5	—	110	220		ns
	10	—	40	80		
Minimum Setup Time: J/ \bar{K} Lines	15	—	30	60	ns	
	5	—	70	140		ns
	10	—	25	50		
Parallel-In-Lines	15	—	20	40	ns	
	5	2	4	—		MHz
	10	6	12	—		
Maximum Clock Frequency, f_{CL}	15	8	16	—	MHz	
	5	—	5	7.5		pF
	10	—	5	7.5		
Input Capacitance, C_{IN}	Any Input	—	5	7.5	pF	
RESET OPERATION						
Propagation Delay Time: t_{PHL}, t_{PLH}	5	—	230	460	ns	
	10	—	100	200		
	15	—	80	160		
Minimum Reset Pulse Width, t_{W}	5	—	125	250	ns	
	10	—	55	110		
	15	—	40	40		

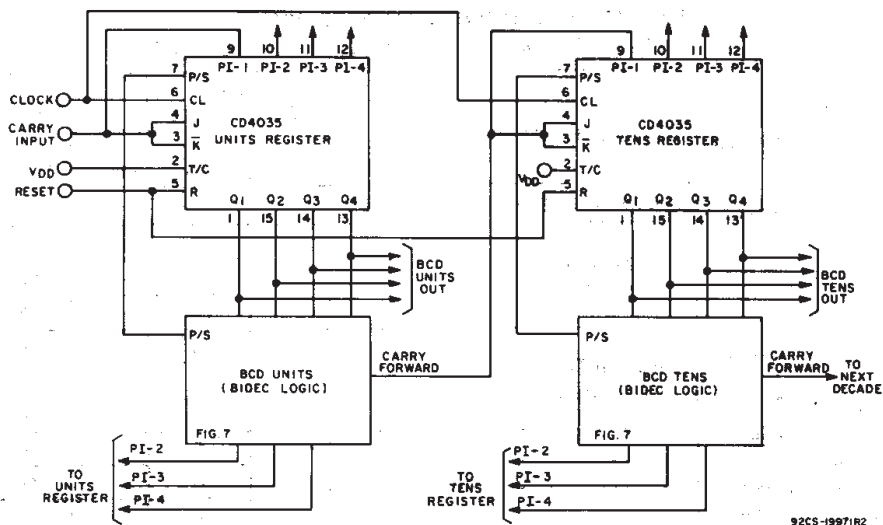
*If more than one unit is cascaded t_{rCL} should be made less than or equal to the sum of the transition time and the fixed propagation delay of the output of the driving stage for the estimated capacitive load.

Control # E =	0				1			
	Q ₁	Q ₂	Q ₃	Q ₄	Q ₁	Q ₂	Q ₃	Q ₄
	A	B	C	D	A	B	C	D
0	0	0	0	0	15	1	1	1
1	1	0	0	0	14	0	1	1
2	0	1	0	0	13	1	0	1
5	1	0	1	0	10	0	1	0
10	0	1	0	1	5	1	0	1
4	0	0	1	0	11	1	1	0
9	1	0	0	1	6	0	1	0
3	1	1	0	0	12	0	0	1
6	0	1	1	0	9	1	0	0
13	1	0	1	1	2	0	1	0
11	1	1	0	1	4	0	0	1
7	1	1	1	0	8	0	0	1
14	0	1	1	1	1	1	0	0
12	0	0	1	1	3	1	1	0
8	0	0	0	1	7	1	1	0

Using a control line (E) two different state sequences can be generated. For example, suppose the following two sequences are desired on command (control line E)

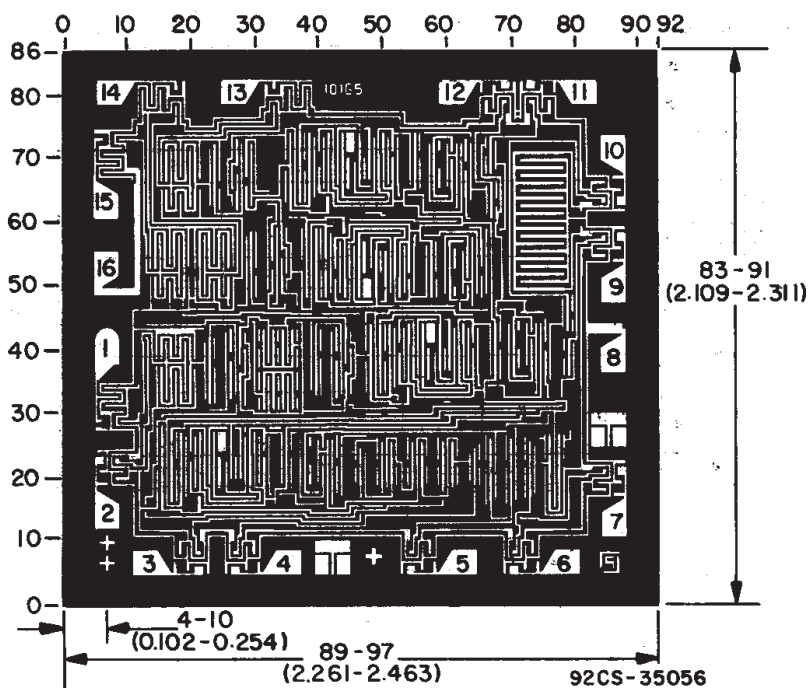
Fig. 16(b) - State sequences.

CD4035B Types

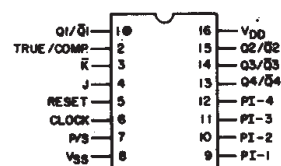


92CS-19971R2

Fig. 17 - Binary-to-BCD converter.



TERMINAL DIAGRAM Top View



92CS-20748A1

Dimensions and pad layout for CD4035BH.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

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